

ULN2003/ULN2004 Seven Darlington array

Description

The ULN2003, ULN2004, are high voltage, high current Darlington arrays each containing seven open collector Darlington pairs with common emitters. Each channel rated at 500 mA and can withstand peak currents of 600 mA. Suppression diodes are included for inductive load driving and the inputs are pinned opposite the outputs to simplify board layout.

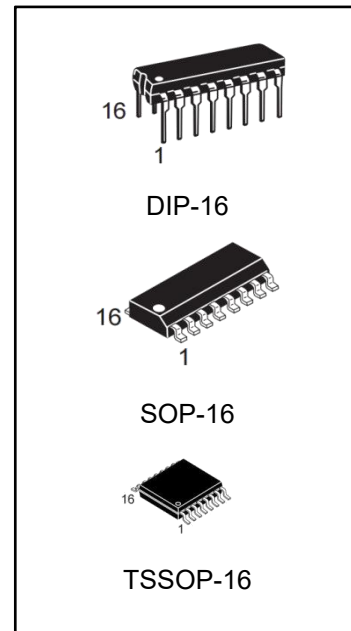
The versions interface to all common logic families:

- ULN2003 (5 V TTL, CMOS)
- ULN2004 (6 - 15 V CMOS, PMOS)

These versatile devices are useful for driving a wide range of loads including solenoids, relays DC motors, LED displays filament lamps, thermal printheads and high power buffers.

The ULN2003/2004 are supplied in 16 pin plastic DIP packages with a copper leadframe to reduce thermal resistance.

They are available also in small outline package (SOP-16) as ULN2003D/2004D



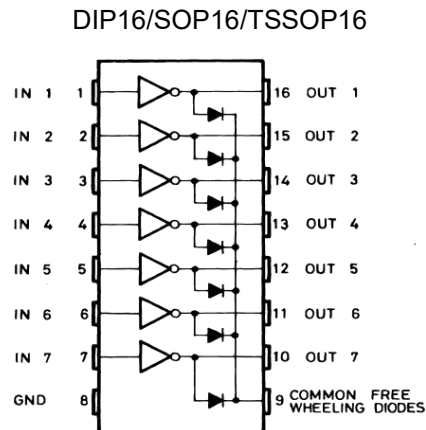
Features

- Seven Darlingtontons per package
- Output current 500 mA per driver (600 mA peak)
- Output voltage 50 V
- Integrated suppression diodes for inductive loads
- Outputs can be paralleled for higher current
- TTL/CMOS/PMOS/DTL compatible inputs
- Inputs pinned opposite outputs to simplify layout

Ordering Information

DEVICE	Package Type	MARKING	Packing	Packing Qty
ULN2003PG	DIP-16	ULN2003	TUBE	1000pcs/Box
ULN2004PG	DIP-16	ULN2004	TUBE	1000pcs/Box
ULN2003DRG	SOP-16	ULN2003	REEL	2500pcs/Reel
ULN2004DRG	SOP-16	ULN2004	REEL	2500pcs/Reel
ULN2003PWRG	TSSOP-16	ULN2003	REEL	2500pcs/Reel
ULN2004PWRG	TSSOP-16	ULN2004	REEL	2500pcs/Reel

Pin configuration



Absolute maximum ratings

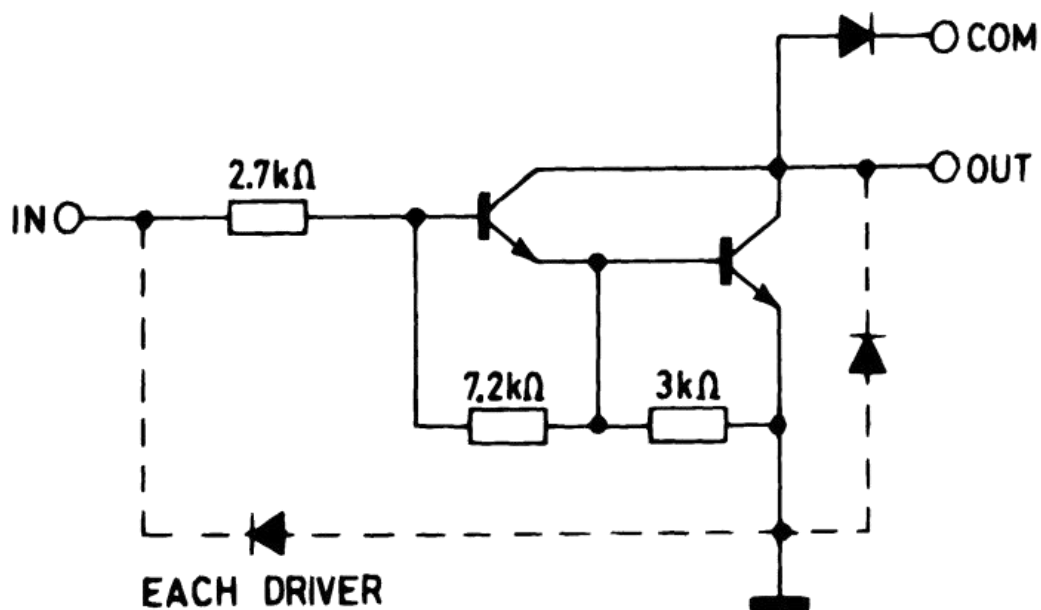
Symbol	Parameter	Value	Unit
V_O	Output voltage	50	V
V_I	Input voltage (for ULN2003 - 2004)	30	V
I_C	Continuous collector current	500	mA
I_B	Continuous base current	25	mA
T_A	Operating ambient temperature range	- 40 to 85	°C
T_{STG}	Storage temperature range	- 55 to 150	°C
T_J	Junction temperature	150	°C

Thermal data

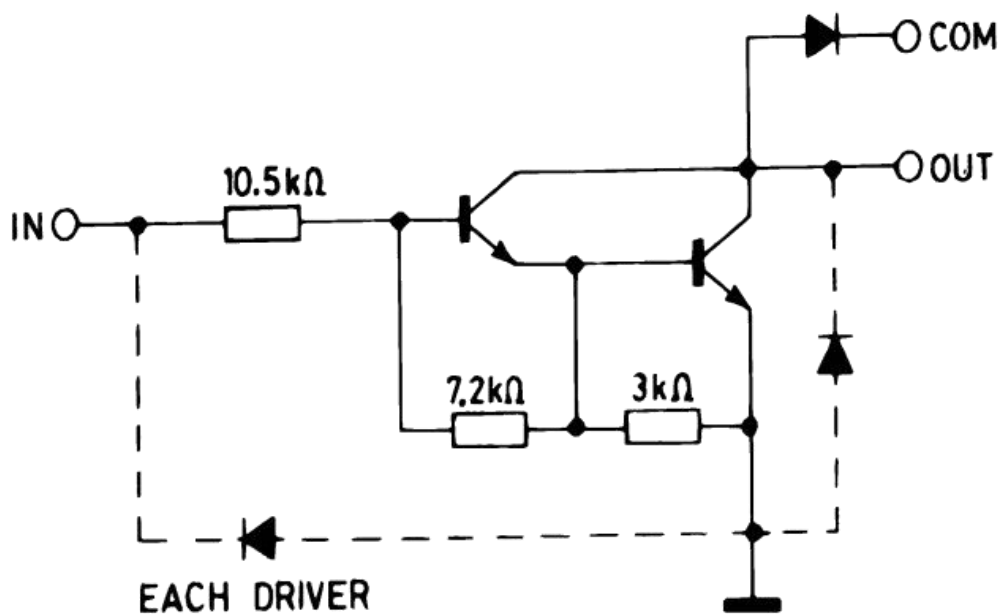
Symbol	Parameter	DIP-16	SOP-16	Unit
R_{thJA}	Thermal resistance junction-ambient, Max.	70	120	°C/W

Diagram

Schematic diagram



ULN2003 (each driver)



ULN2004 (each driver)

Electrical characteristics

$T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Test condition	Min	Typ	Max	Unit
I_{CEX}	Output leakage current	$V_{CE} = 50\text{ V}$, (Figure 1.)			50	μA
		$T_A = 85^{\circ}\text{C}$, $V_{CE} = 50\text{ V}$ (Figure 1.)			100	
		$T_A = 85^{\circ}\text{C}$ for ULN2002, $V_{CE} = 50\text{ V}$, $V_I = 6\text{ V}$ (Figure 2.)			500	
		$T_A = 85^{\circ}\text{C}$ for ULN2002, $V_{CE} = 50\text{ V}$, $V_I = 1\text{ V}$ (Figure 2.)			500	
$V_{CE(SAT)}$	Collector-emitter saturation voltage (Figure 3.)	$I_C = 100\text{ mA}$, $I_B = 250\text{ }\mu\text{A}$		0.9	1.1	V
		$I_C = 200\text{ mA}$, $I_B = 350\text{ }\mu\text{A}$		1.1	1.3	
		$I_C = 350\text{ mA}$, $I_B = 500\text{ }\mu\text{A}$		1.3	1.6	
$I_{I(ON)}$	Input current (Figure 4.)	for ULN2002, $V_I = 17\text{ V}$		0.82	1.25	mA
		for ULN2003, $V_I = 3.85\text{ V}$		0.93	1.35	
		for ULN2004, $V_I = 5\text{ V}$		0.35	0.5	
		$V_I = 12\text{ V}$		1	1.45	
$I_{I(OFF)}$	Input current (Figure 5.)	$T_A = 85^{\circ}\text{C}$, $I_C = 500\text{ }\mu\text{A}$	50	65		μA
$V_{I(ON)}$	Input voltage (Figure 6.)	$V_{CE} = 2\text{ V}$, for ULN2002 $I_C = 300\text{ mA}$ for ULN2003 $I_C = 200\text{ mA}$ $I_C = 250\text{ mA}$ $I_C = 300\text{ mA}$ for ULN2004 $I_C = 125\text{ mA}$ $I_C = 200\text{ mA}$ $I_C = 275\text{ mA}$ $I_C = 350\text{ mA}$			13 2.4 2.7 3 5 6 7 8	V
h_{FE}	DC Forward current gain(Figure 3.)	for ULN2001, $V_{CE} = 2\text{ V}$, $I_C = 350\text{ mA}$	1000			
C_I	Input capacitance			15	25	pF
t_{PLH}	Turn-on delay time	0.5 V_I to 0.5 V_O		0.25	1	μs
t_{PHL}	Turn-off delay time	0.5 V_I to 0.5 V_O		0.25	1	μs
I_R	Clamp diode leakage current(Figure 7.)	$V_R = 50\text{ V}$			50	μA
		$T_A = 85^{\circ}\text{C}$, $V_R = 50\text{ V}$			100	
V_F	Clamp diode forward voltage(Figure 8.)	$I_F = 350\text{ mA}$		1.7	2	V

Test circuits

Figure 1. Output leakage current

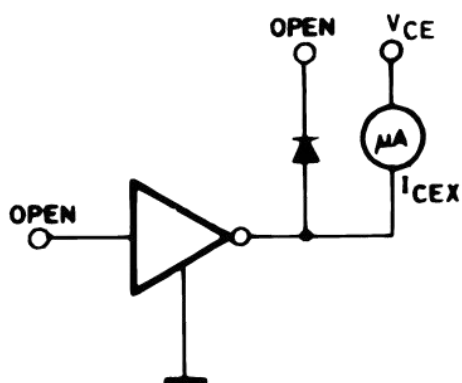


Figure 2. Output leakage current

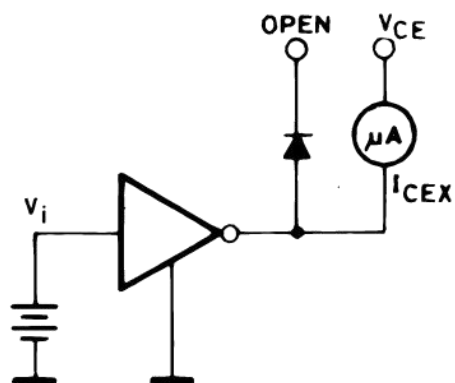


Figure 3. Collector-emitter saturation voltage

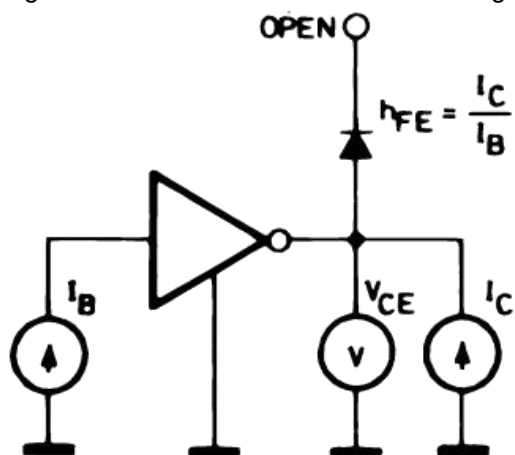


Figure 4. Input current (ON)

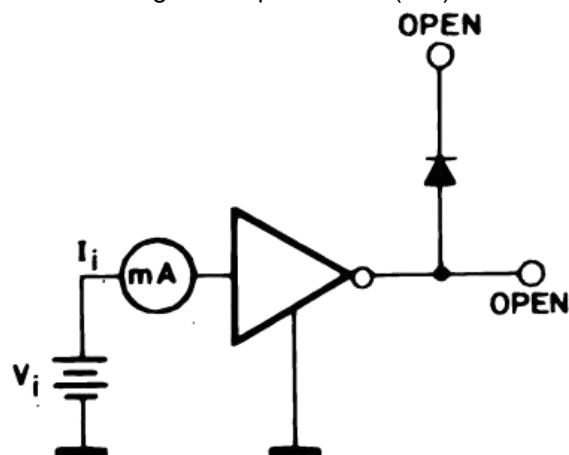


Figure 5. Input current (OFF)

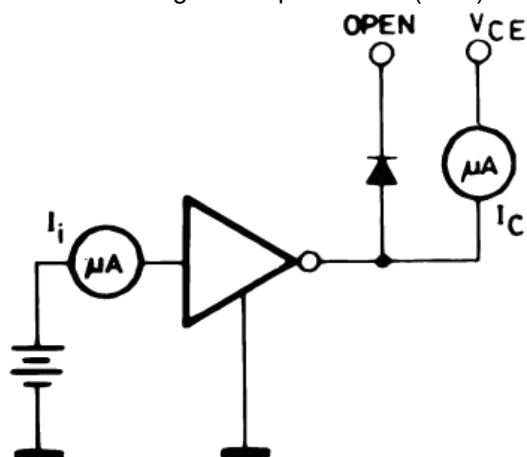


Figure 6. Input voltage

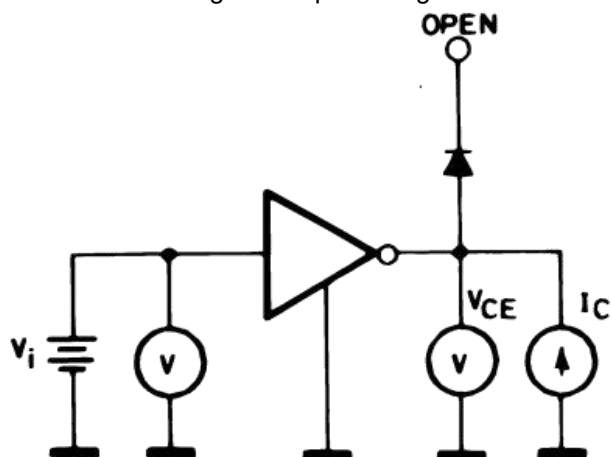


Figure 7. Clamp diode leakage current

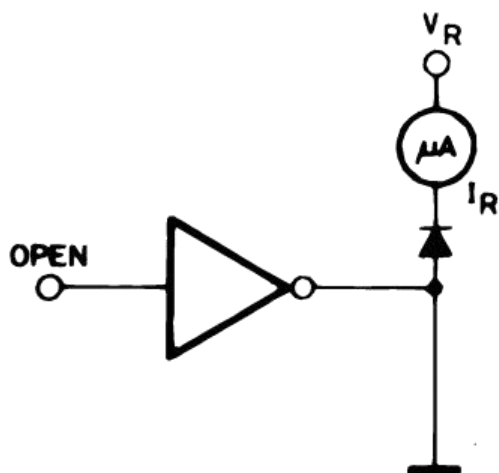
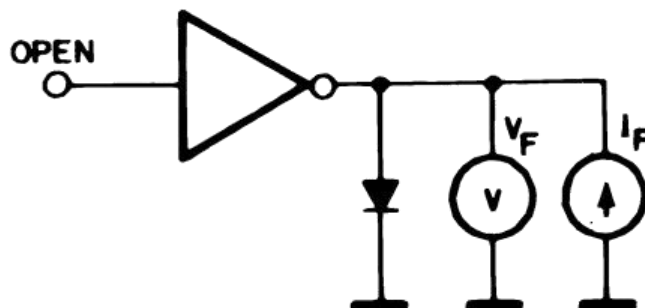


Figure 8. Clamp diode forward voltage



Typical performance characteristics

Figure 9. Collector current vs. saturation voltage ($T_J = 25^\circ\text{C}$)

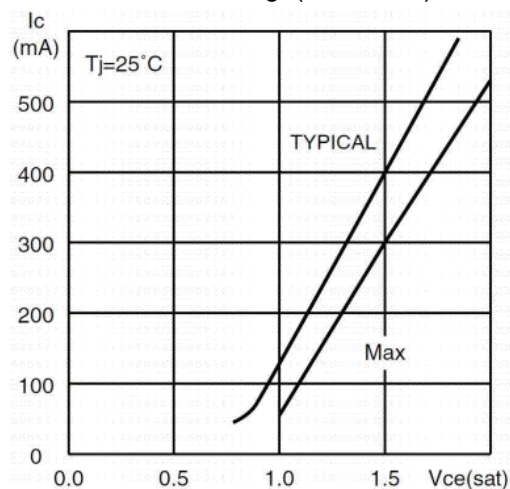


Figure 10. Collector current vs. saturation voltage

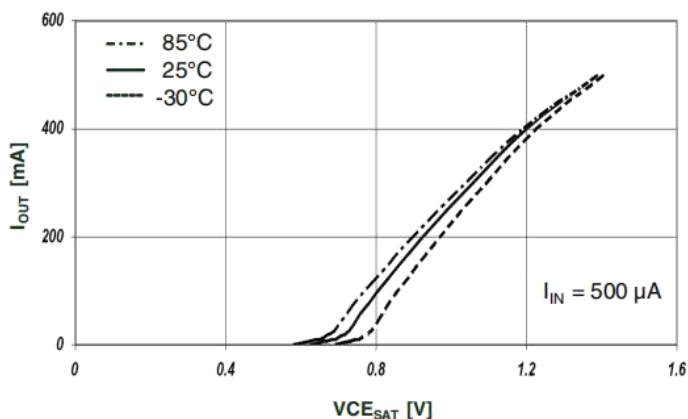


Figure 11. Input current vs. input voltage

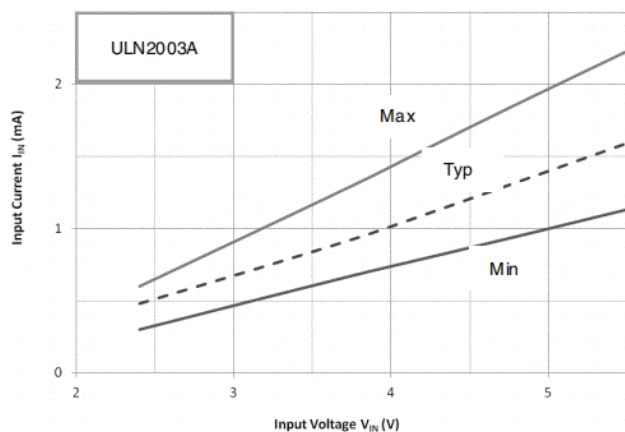


Figure 12. Input current vs. input voltage ($T_a = 25^\circ\text{C}$)

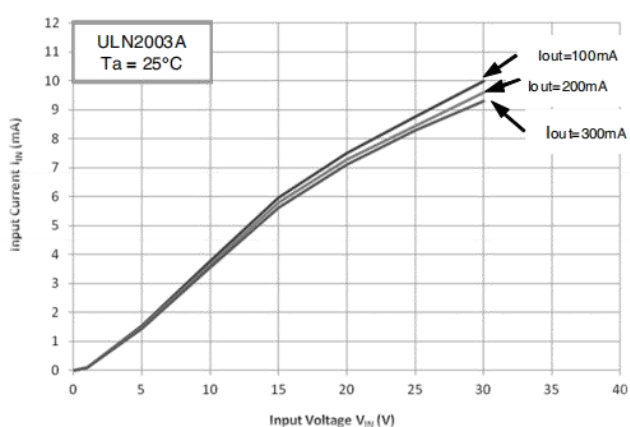


Figure 13. Collector current vs. input current

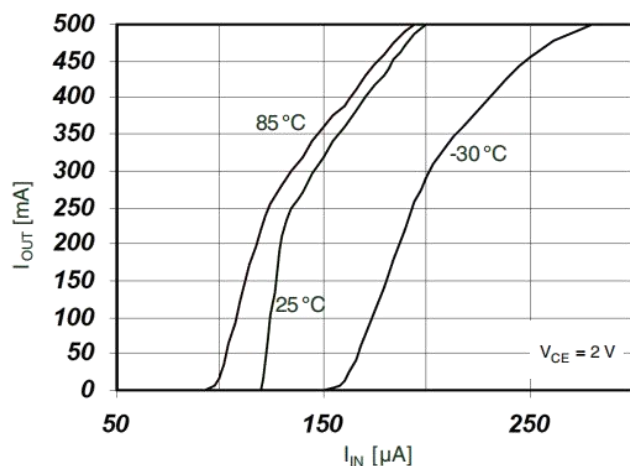
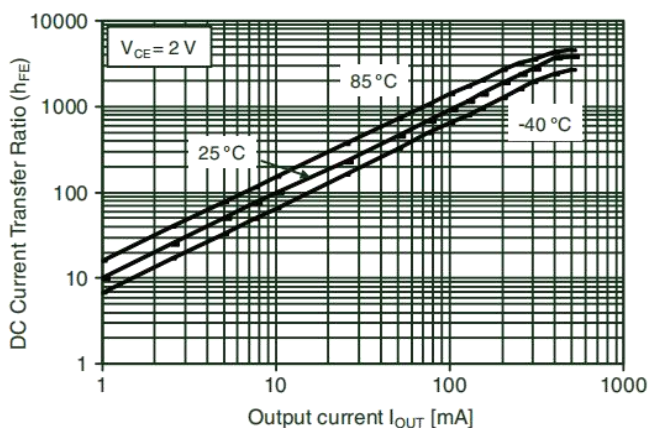


Figure 14. h_{FE} vs. output current



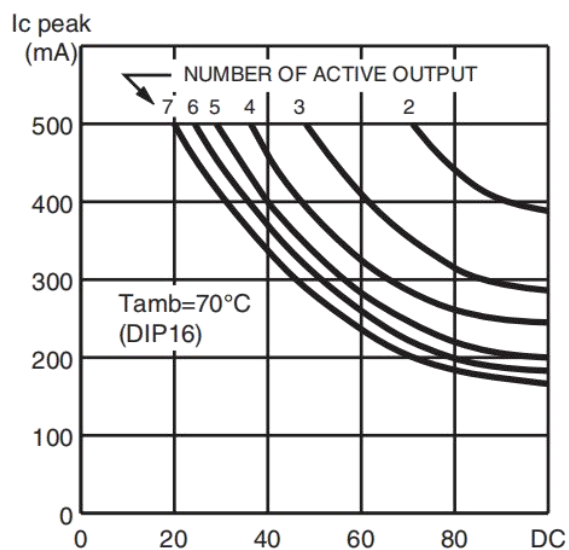


Figure 15. Peak collector current vs. duty cycle (DIP-16)

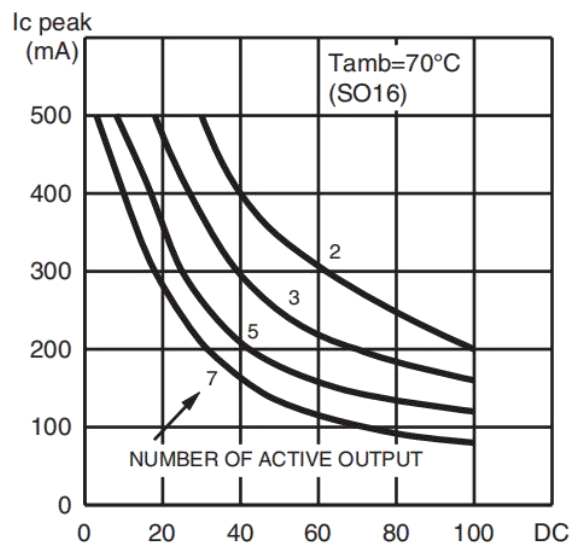
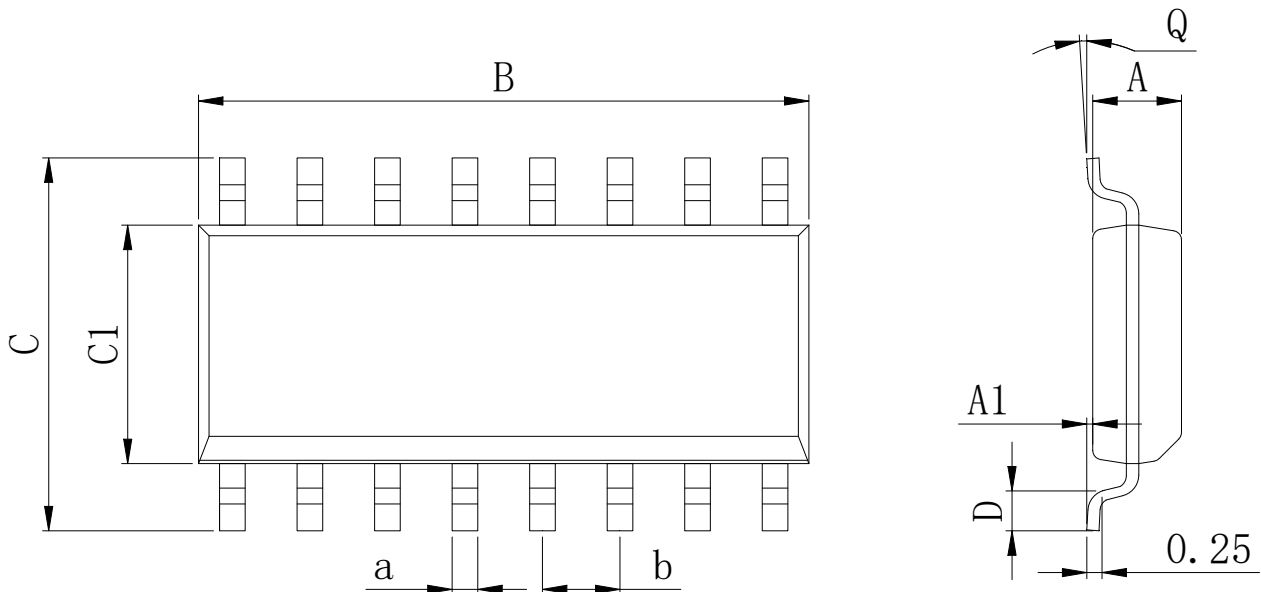


Figure 16. Peak collector current vs. duty cycle (SO-16)

Physical Dimensions

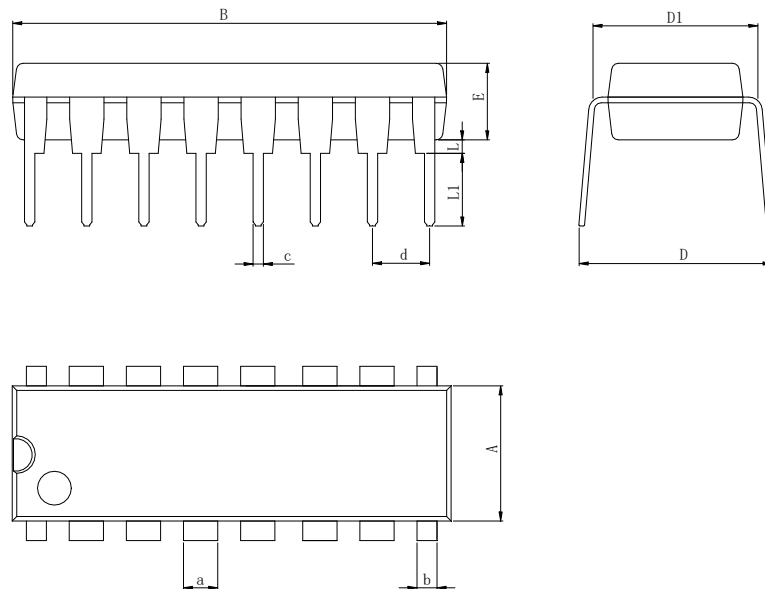
SOP16



Dimensions In Millimeters(SOP16)

Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	1.35	0.05	9.80	5.80	3.80	0.40	0°	0.35	1.27 BSC
Max:	1.55	0.20	10.0	6.20	4.00	0.80	8°	0.45	

DIP16

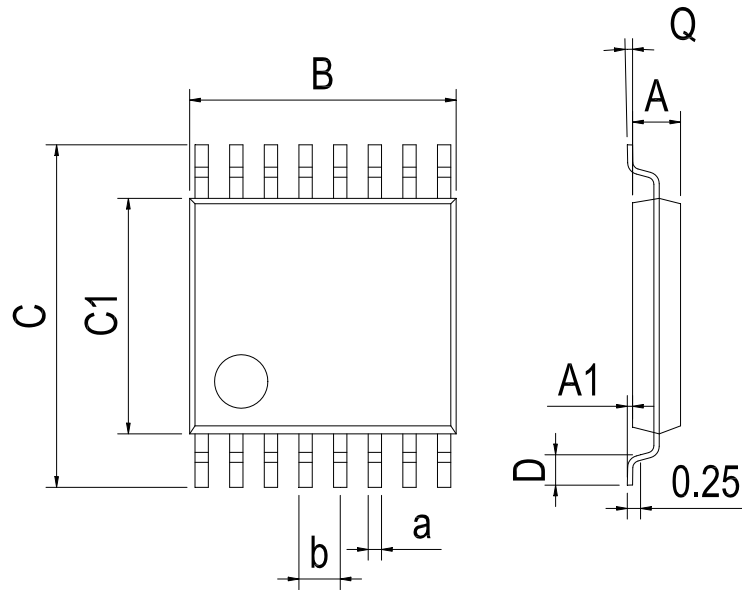


Dimensions In Millimeters(DIP16)

Symbol:	A	B	D	D1	E	L	L1	a	b	c	d
Min:	6.10	18.94	8.40	7.42	3.10	0.50	300	1.50	0.85	0.40	2.54 BSC
Max:	6.68	19.56	9.00	7.82	3.55	0.70	3.60	1.55	0.90	0.50	

Physical Dimensions

TSSOP16



Dimensions In Millimeters(TSSOP16)									
Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	0.85	0.05	4.90	6.20	4.30	0.40	0°	0.20	0.65 BSC
Max:	0.95	0.20	5.10	6.60	4.50	0.80	8°	0.25	

Revision History

DATE	REVISION	PAGE
2018-8-21	New	1-12

IMPORTANT STATEMENT:

Hanschip Semiconductor reserves the right to change its products and services without notice. Before ordering, the customer shall obtain the latest relevant information and verify whether the information is up to date and complete. Hanschip Semiconductor does not assume any responsibility or obligation for the altered documents.

Customers are responsible for complying with safety standards and taking safety measures when using Hanschip Semiconductor products for system design and machine manufacturing. You will bear all the following responsibilities: select the appropriate Hanschip Semiconductor products for your application; Design, validate and test your application; Ensure that your application meets the appropriate standards and any other safety, security or other requirements. To avoid the occurrence of potential risks that may lead to personal injury or property loss.

Hanschip Semiconductor products have not been approved for applications in life support, military, aerospace and other fields, and Hanschip Semiconductor will not bear the consequences caused by the application of products in these fields. All problems, responsibilities and losses arising from the user's use beyond the applicable area of the product shall be borne by the user and have nothing to do with Hanschip Semiconductor, and the user shall not claim any compensation liability against Hanschip Semiconductor by the terms of this Agreement.

The technical and reliability data (including data sheets), design resources (including reference designs), application or other design suggestions, network tools, safety information and other resources provided for the performance of semiconductor products produced by Hanschip Semiconductor are not guaranteed to be free from defects and no warranty, express or implied, is made. The use of testing and other quality control technologies is limited to the quality assurance scope of Hanschip Semiconductor. Not all parameters of each device need to be tested.

The documentation of Hanschip Semiconductor authorizes you to use these resources only for developing the application of the product described in this document. You have no right to use any other Hanschip Semiconductor intellectual property rights or any third party intellectual property rights. It is strictly forbidden to make other copies or displays of these resources. You should fully compensate Hanschip Semiconductor and its agents for any claims, damages, costs, losses and debts caused by the use of these resources. Hanschip Semiconductor accepts no liability for any loss or damage caused by infringement.